

CVD Diamond Sensors for the Beam Calorimeter of the ILC



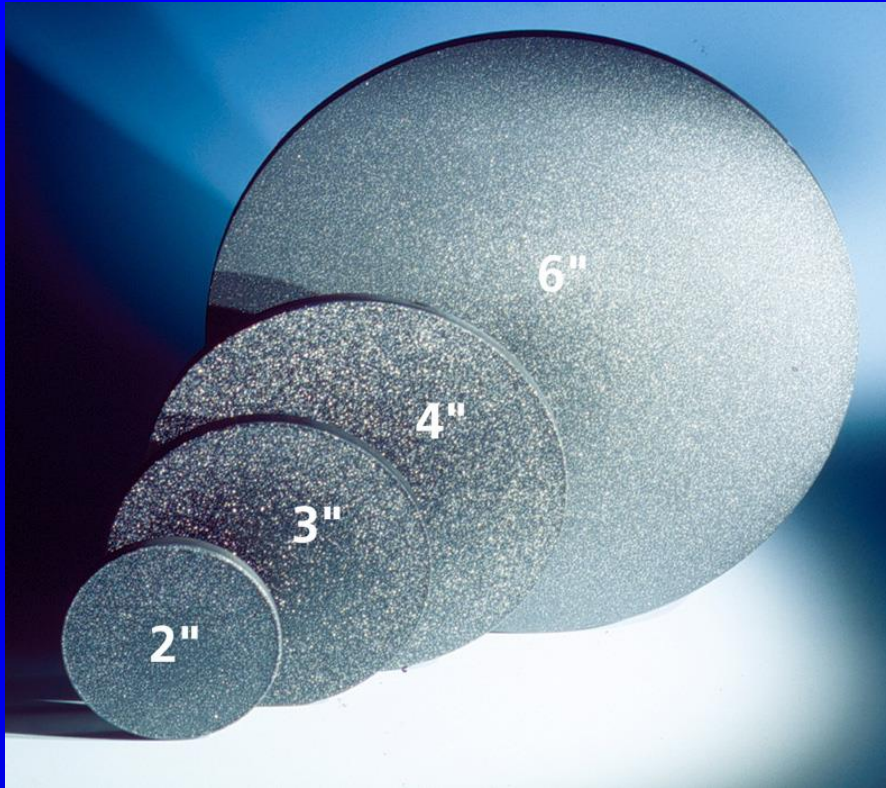
FCAL Collaboration Workshop
TAU, September 18-19, 2005

Outline

- Prototyping activities on diamond sensors:
 - FAP7 series from Fraunhofer IAF
 - E6_4p remetalized and CCD vs dose
 - FAP5

- Summary & outlook

pCVD Diamond Production

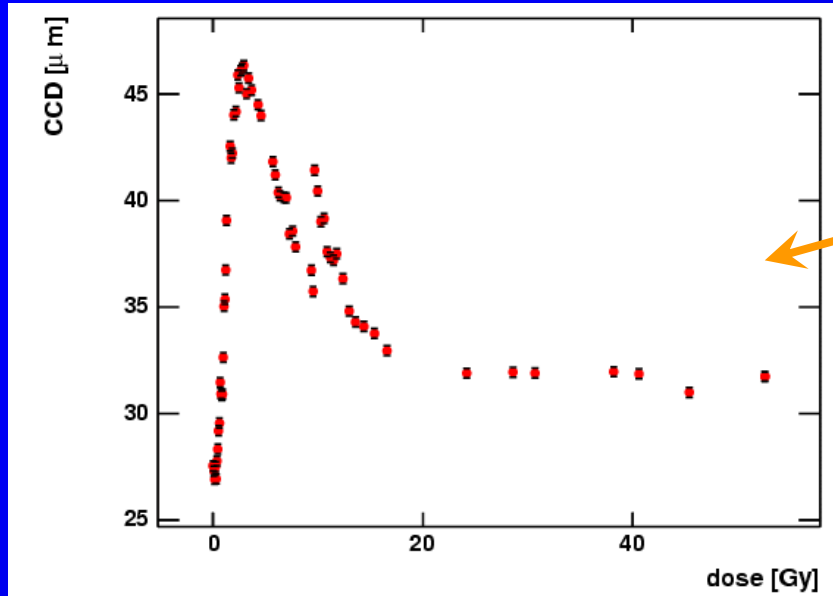


polycrystalline CVD diamond wafer
(Photo: IAF)

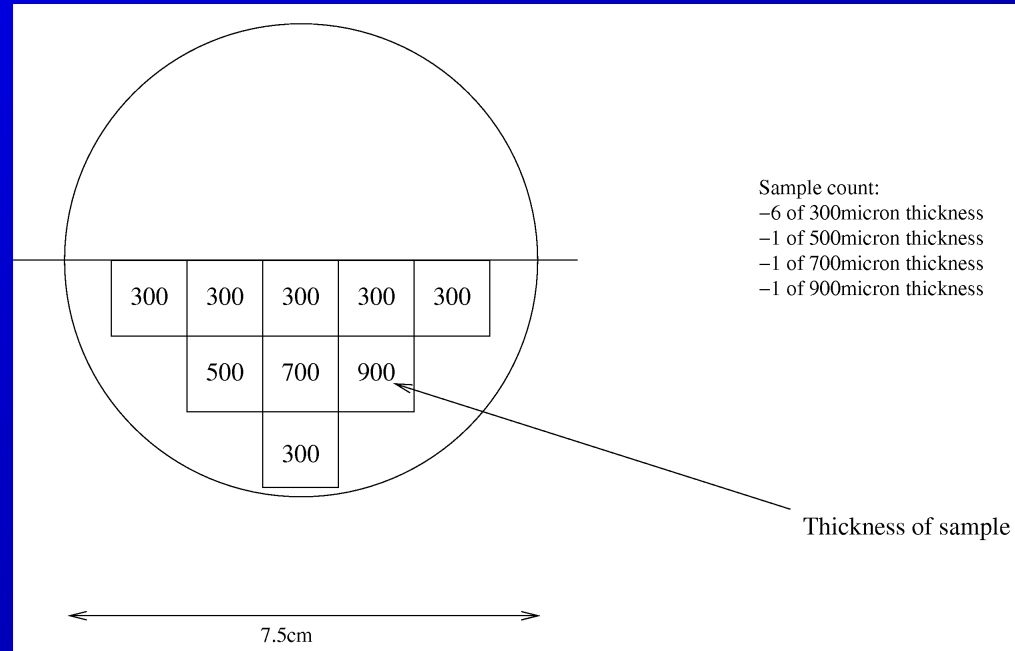
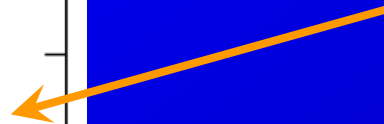


Single crystal CVD diamonds are not (yet) available on wafer scale.

Investigation of FAP7 series



In 2004 we got a promising sensor from Freiburg, FAP6.



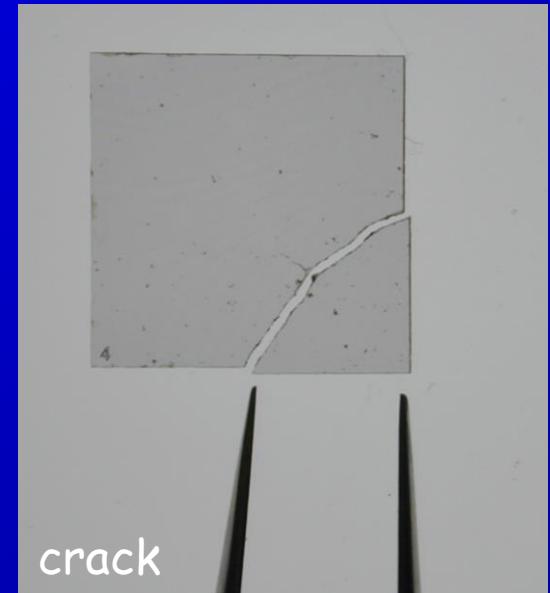
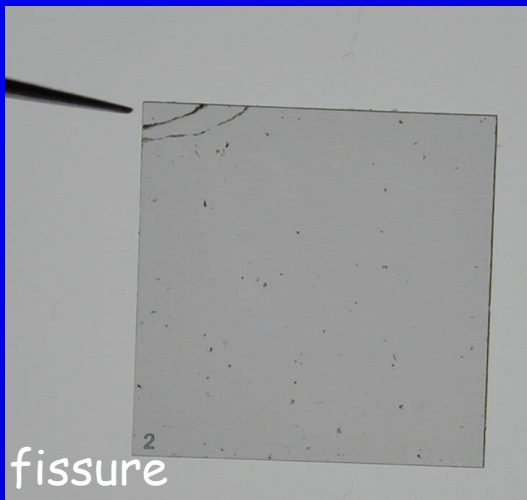
A batch of samples from the same wafer, with comparable performance, was ordered.

The aim was to investigate:

- different thicknesses
- different radii/wafer positions

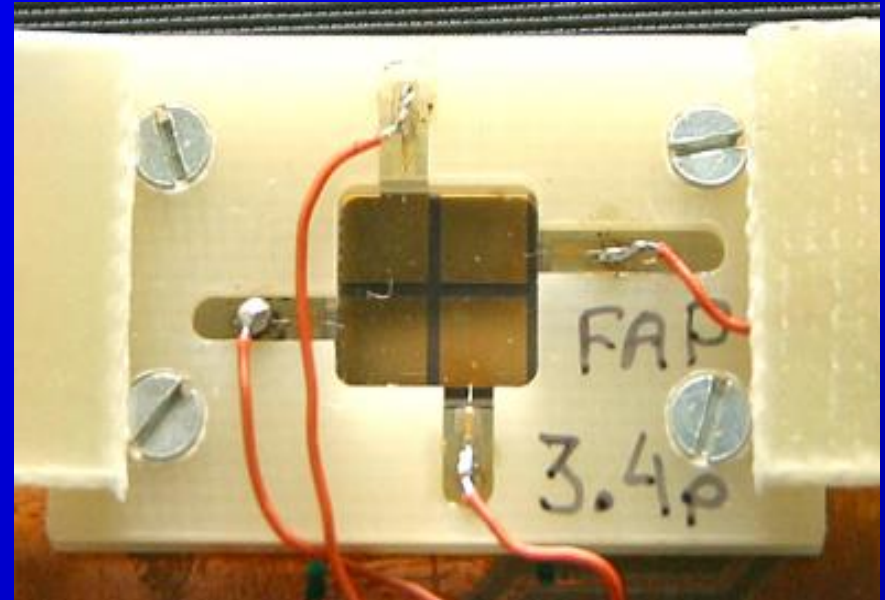
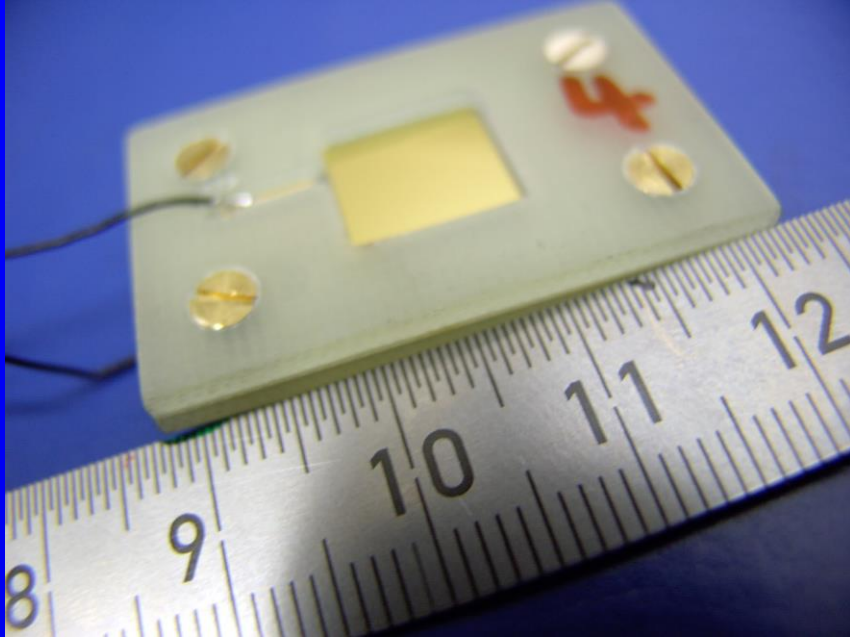
The issues (1)

- Lost samples during the thinning procedure
 - Thinning procedure for singulated samples.
 - High amount of material to be removed.
 - Polycrystalline samples.



- If possible metallization was shrunk or number of pads reduced.
- Replacement sensors were produced. => **Total of 11 samples!**

Diamond Prototyping

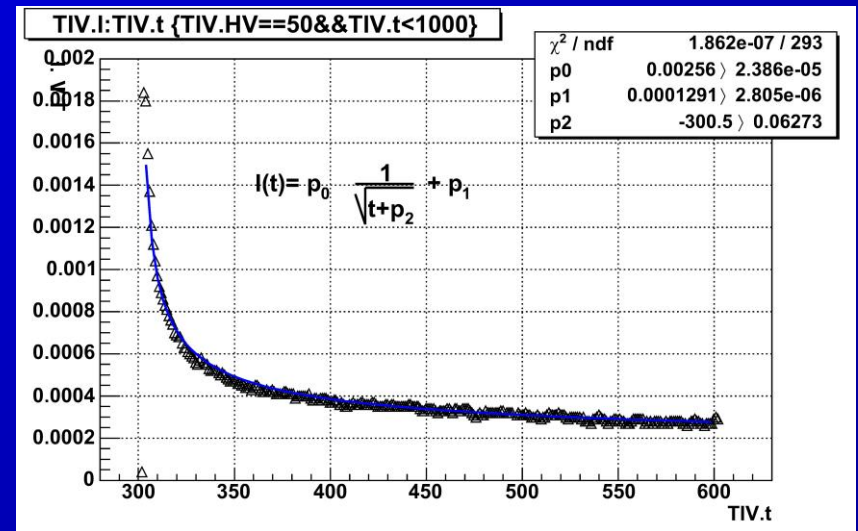
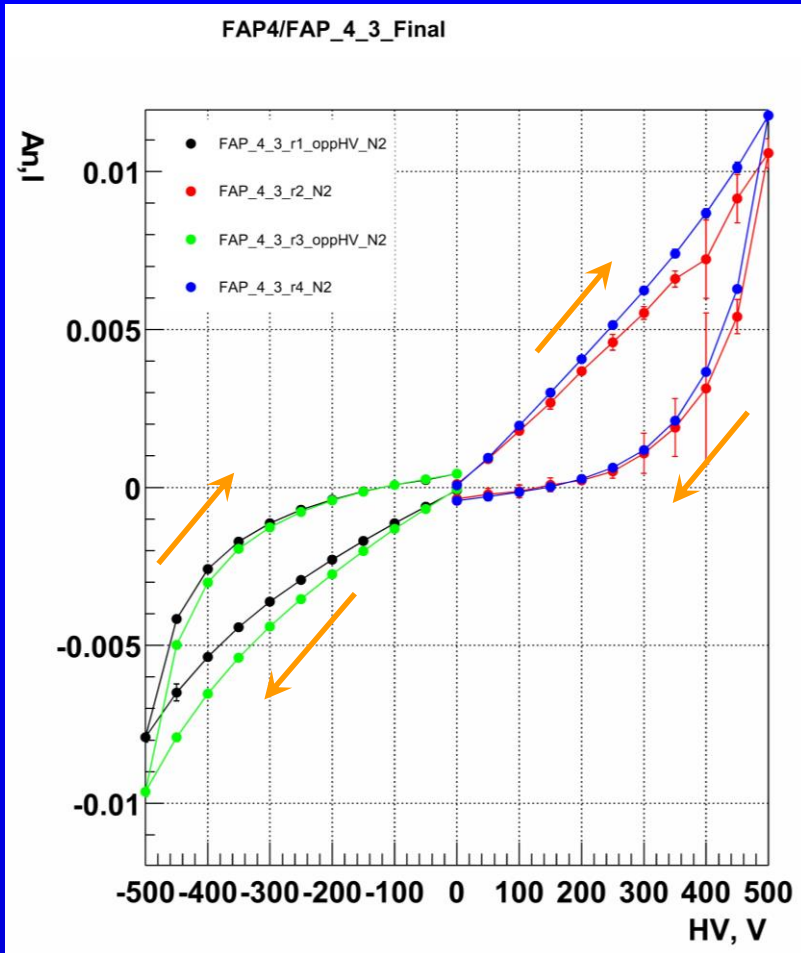


Diamond size: 12x12 mm²

Metallization: 100 nm Ti + 200 nm Pt + 500 nm Au
usually four segments

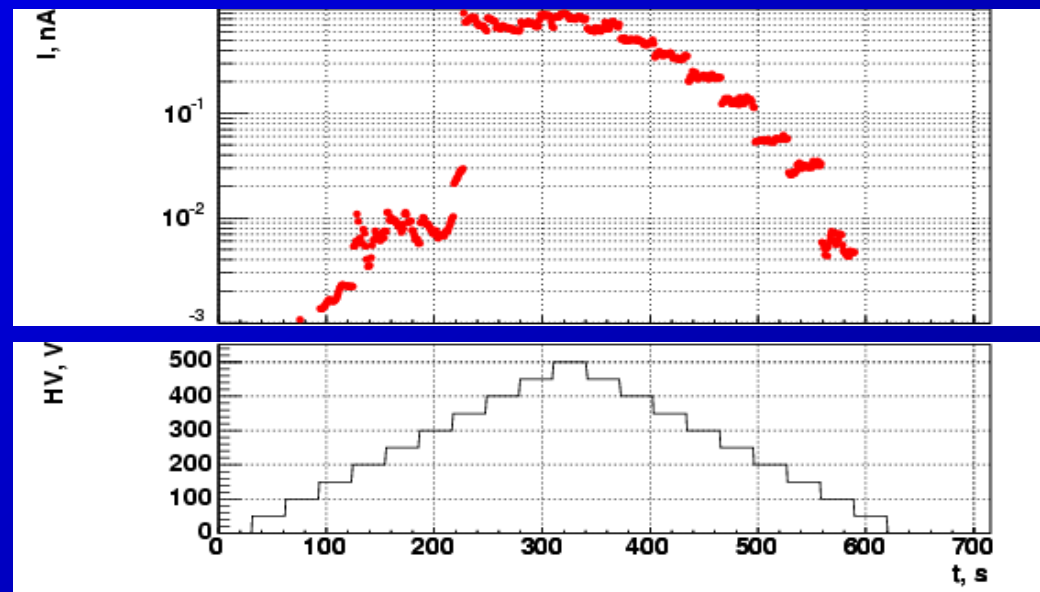
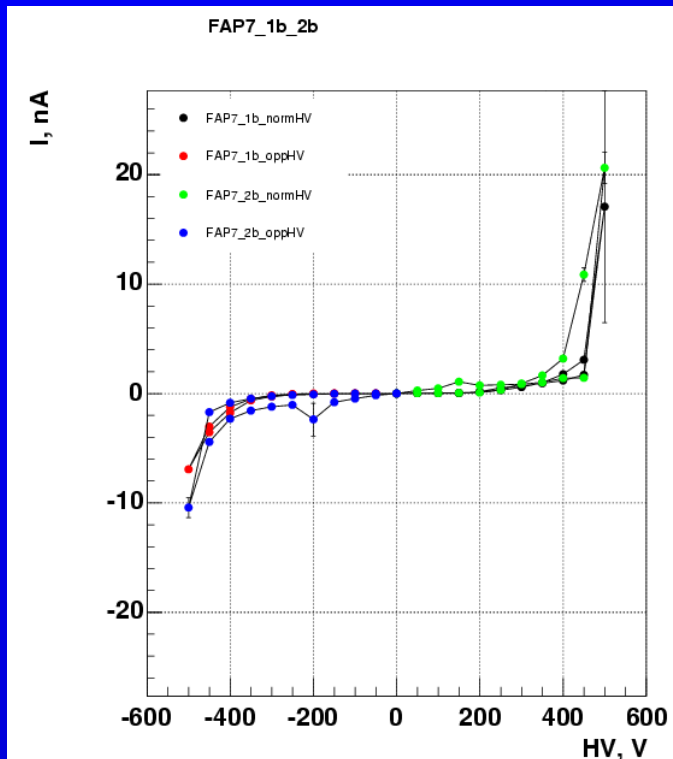
IV Behavior

- IV behavior: ohmic for ramping up/down, hysteresis
- Current $\sim \mu\text{A}$
- $I = I(t) \sim 1/\sqrt{t}$ - dependence

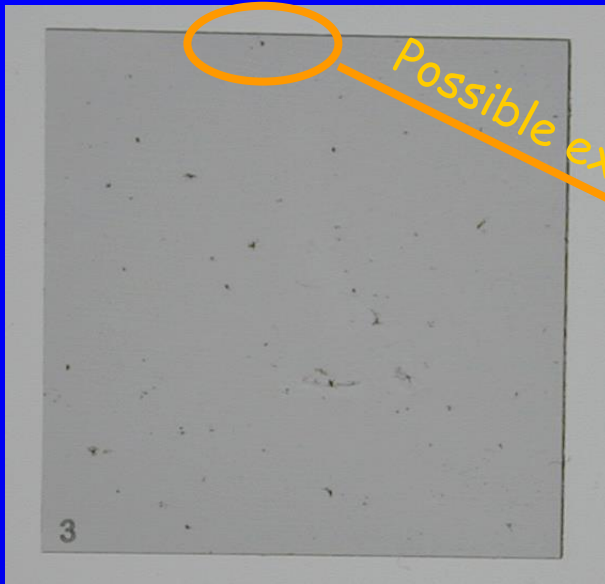


The issues (2)

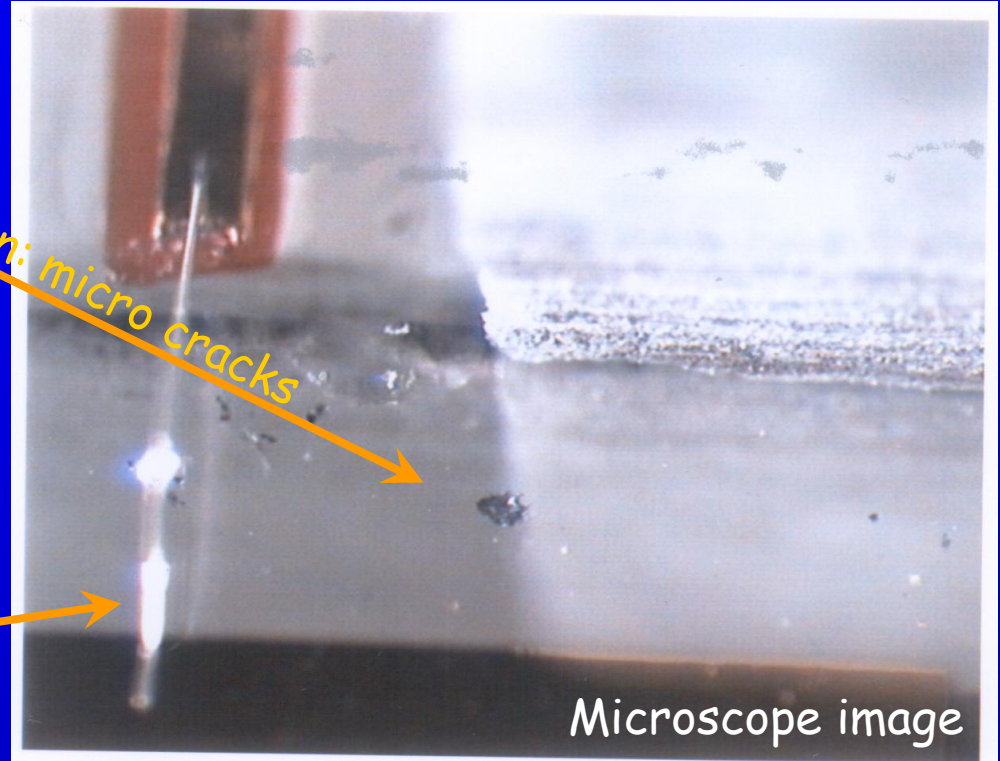
- Large currents in most of the samples of the FAP7 series (8 out of 11).
- These currents originate in single pads.



Origin of isolated breakthroughs



Possible explanation: micro cracks



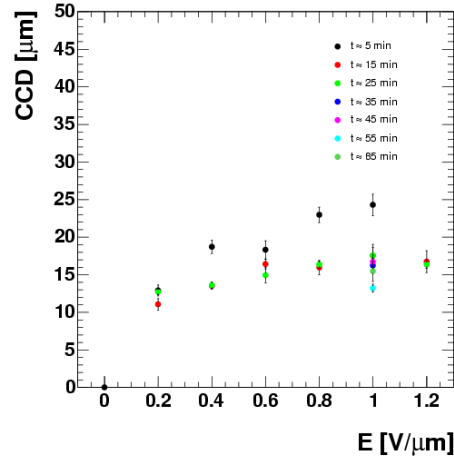
Microscope image

Good: Wire bonding is now reliable.

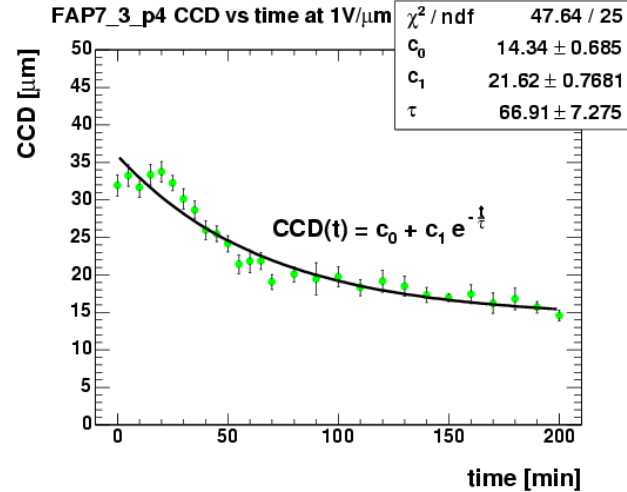
Most of the samples have micro cracks IN their crystal bulk.
IAF: The number of micro cracks increases with wafer thickness and radius on the wafer.

CCD Performance of FAP7 batch

FAP7_3_p4 CCD vs E-field

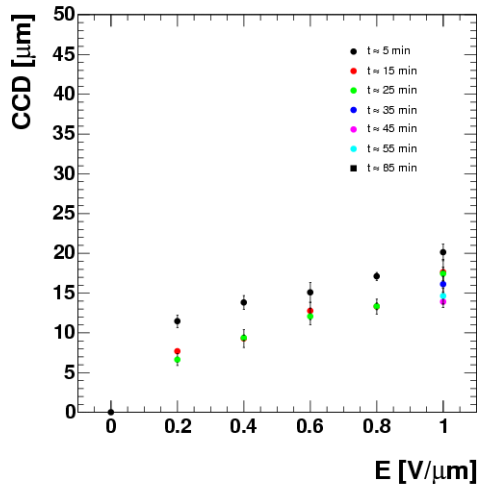


FAP7_3_p4 CCD vs time at $1\text{V}/\mu\text{m}$

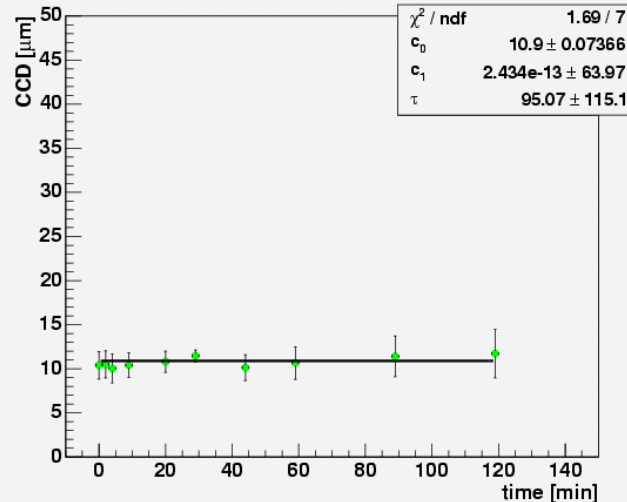


CCD performance of all diamonds from FAP7 is poor, but a signal can still be extracted.

FAP7_7_p3 CCD vs E-field



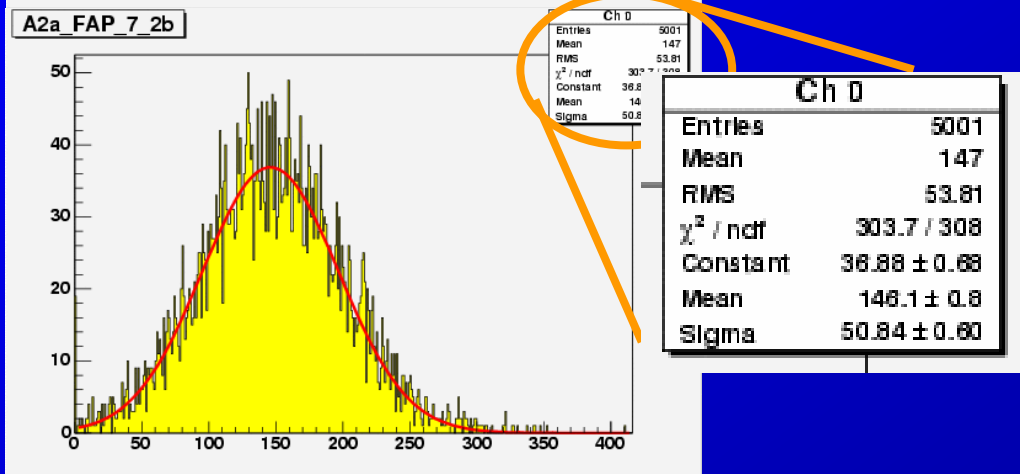
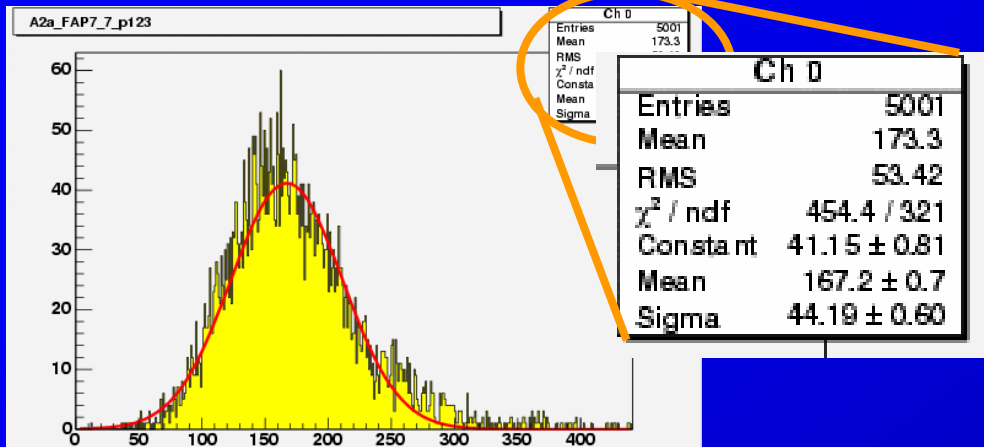
FAP_7_6a CCD vs time at $0.8\text{V}/\mu\text{m}$



In principle, this would be no problem for the BeamCal, but....

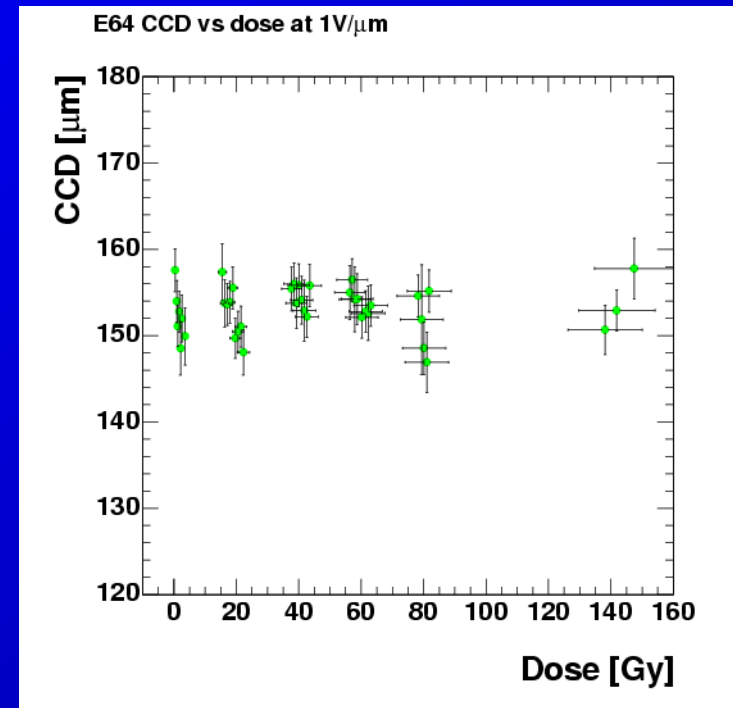
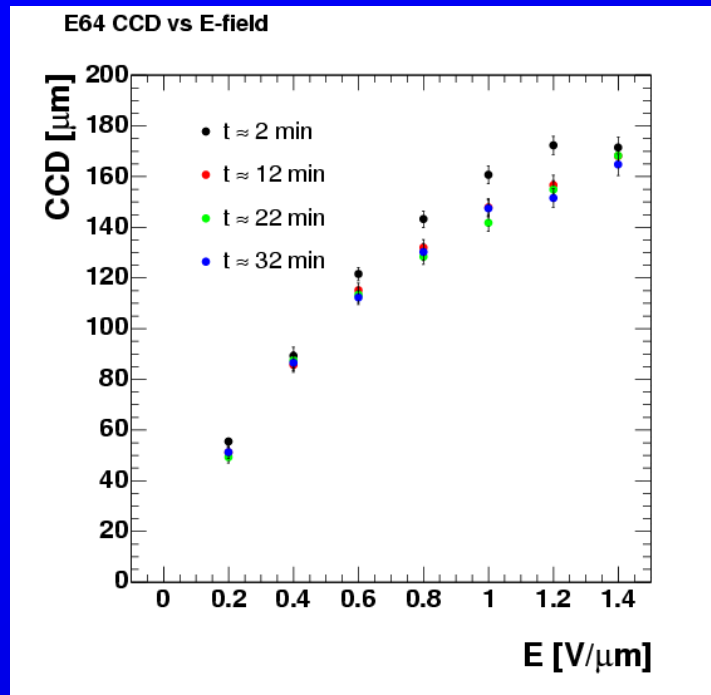
The issues (3)

Major problem: CCD vs Dose behavior of the FAP7 samples.



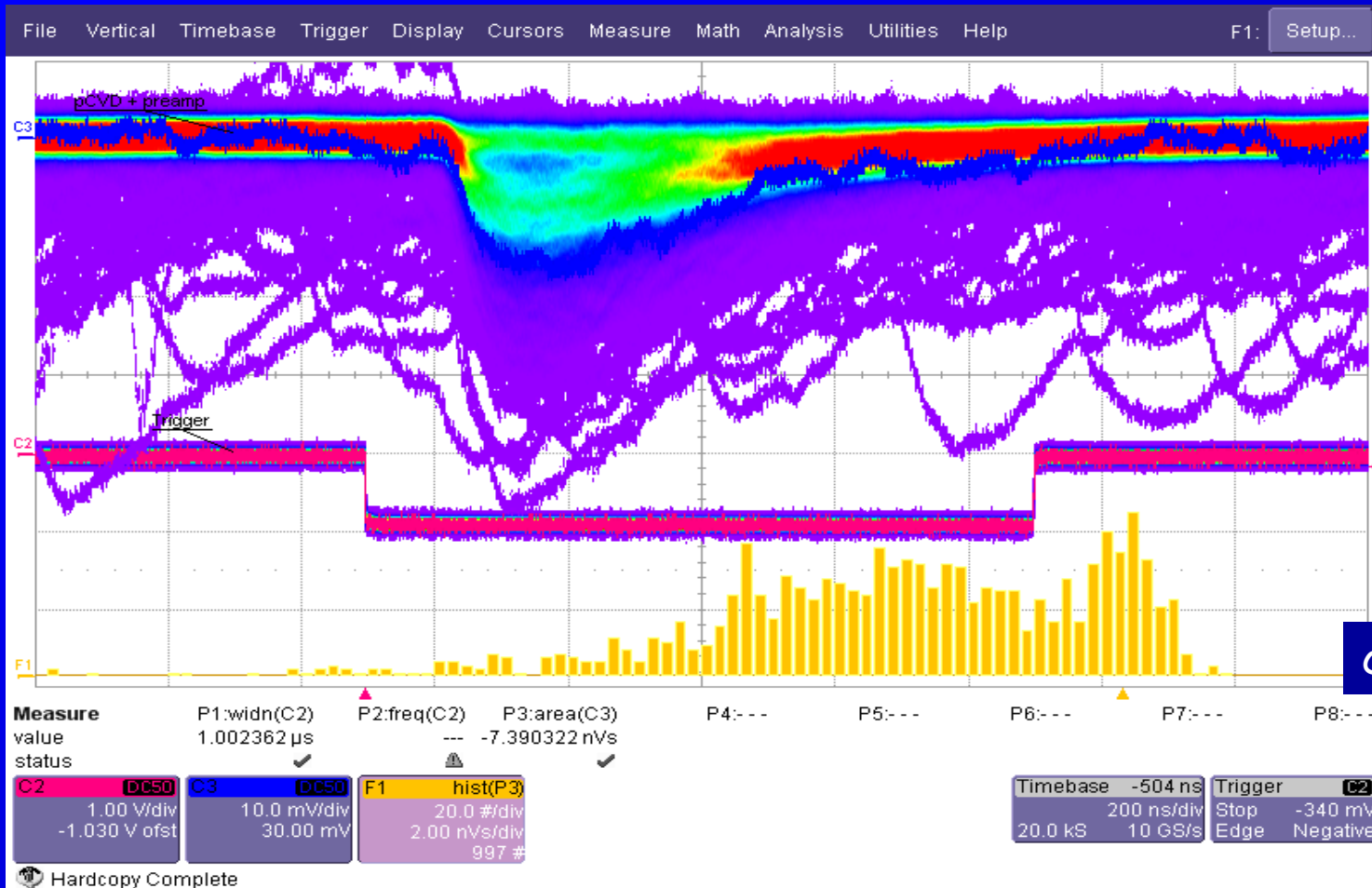
Decrease of signal and increase of noise after ~ 3 Gy.
This is accompanied with increasing current.
The behavior is similar for at least 3 FAP7 samples.

Some Good News - E6_4p



Element 6 sample was remetallized and shows good performance and is stable under irradiation.

E6_4p Signal

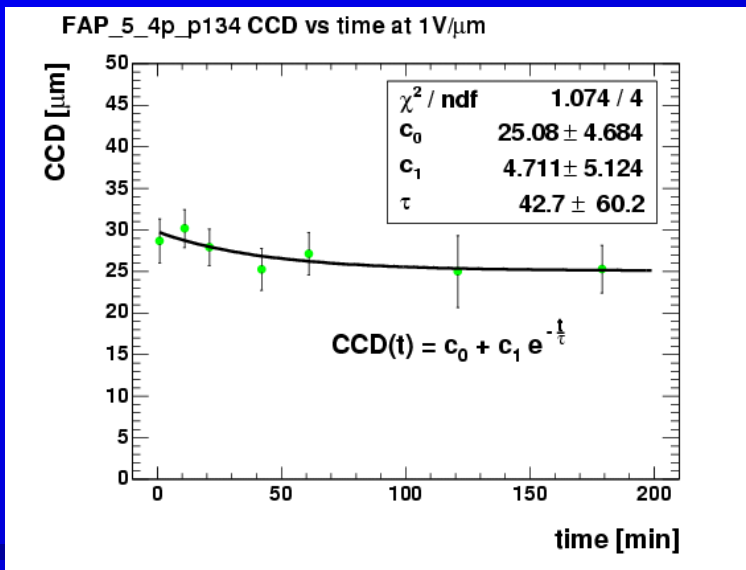
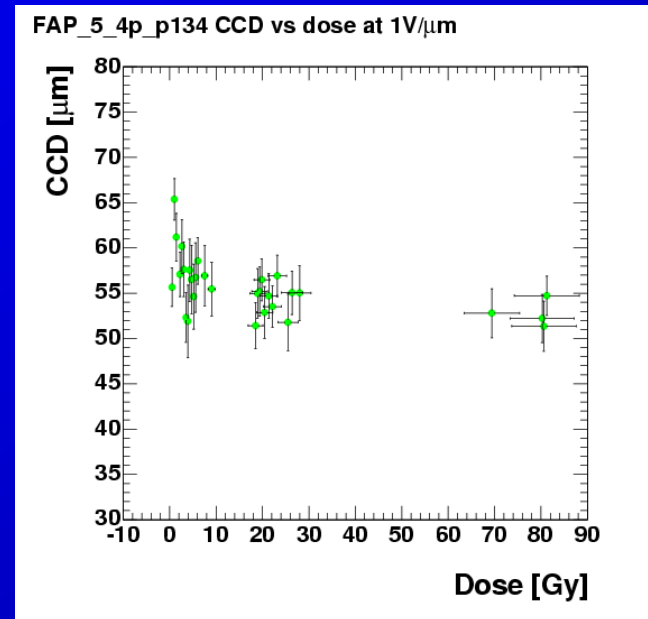
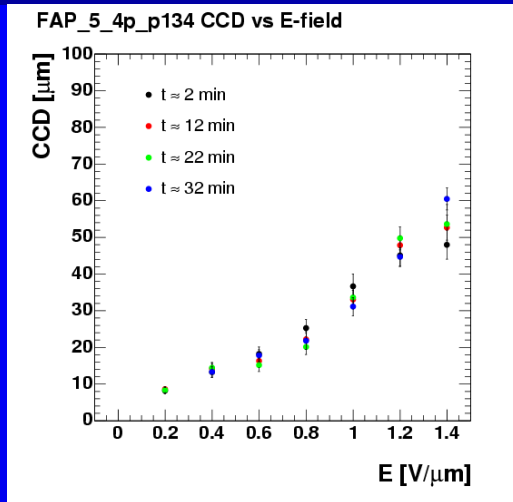


signal (~1000)

trigger

charge histogram

2nd Good Sample from IAF - FAP5



Also FAP5 is stable under irradiation. The efficiency is not very high, but it would be sufficient for BeamCal. Need more samples like this from IAF.

Summary

- FAP 7 batch was not very successful.
 - Thinning problems.
 - Micro cracks and current breakthroughs.
 - CCD vs Dose behavior unsatisfactory.
- Element 6 samples have the best performance.
 - Metallization seems to be of minor importance atm..
- IAF has produced two good samples for us with stable behavior under irradiation.

Outlook

- Need more samples from IAF. FAP5 and 6 are a good starting point...but this was the case before FAP7 batch.
- Avoid thick wafers (~1 mm) to achieve less micro cracks and reliable thinning procedure.
- IAF promised to deliver new samples in October.
- Starting to look into single crystal diamonds. Will get a sample in the next weeks...it's from Element 6.
- Continue to investigate FAP7 batch of sensors.